25 mm (1") encapsulated photomultiplier 9110V02 series data sheet

3

features

voltage divider

high temperature operation

encapsulated in a mu-metal

sleeve with an integral

rugged



description

The 9110V02 encapsulated photomultiplier comprises a 25mm (1") diameter, compact, rugged, end window photomultiplier with a plano-concave window, high temperature blue-green sensitive bialkali photocathode and 10 BeCu dynodes of circular focused design.

The photomultiplier is encapsulated, together with a voltage divider, in a mumetal* sleeve.

This type will operate up to 175°C and has a minimum plateau length of 150 V at 150°C.

2 applications

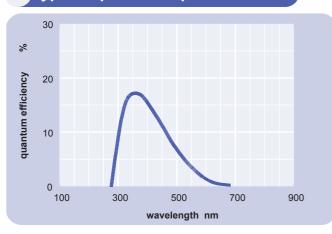
• oil well logging including

measuring while drilling (MWD) x-ray and gamma ray spectroscopy in harsh environments

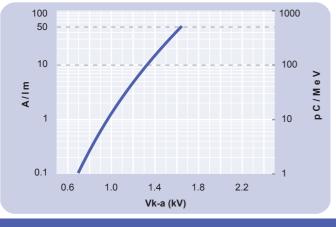
window characteristics

	9110V02 borosilicate	
spectral range* (nm) refractive index (n_d)	280 - 630 1.49	
K (ppm) Th (ppb) U (ppb)	300 250 100	 * wavelength range over which quantum efficiency exceeds 1 % of peak

5 typical spectral response curves



typical voltage gain characteristics 7



characteristics 6

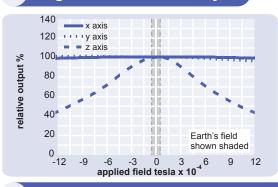
photocathode: high temperature bialkali active diameter quantum efficiency at peak luminous sensitivity with CB filter with CR filter dynodes: 10CFBeCu	mm % ∝A/Im	4	22 17 50 6 5	
anode sensitivity: nominal anode sensitivity max. rated anode sensitivity overall voltage for nominal A/Im overall voltage for max. rated A/Im gain at nominal A/Im dark current at 20 °C:	A/Im A/Im V V x 10 ⁶		10 50 1350 1650 0.2	1500
DC at max. rated A/Im DC at max. rated A/Im pulsed linearity (-5 % deviation): divider A resolution:	nA nA mA		0.1 0.5 20	1
¹³⁷ Cs with 1.0 " dia x 1.5 " Nal(TI) temperature coefficient: timing: multi-electron rise time multi-electron fwhm single electron rise time	% °C ⁻¹ ns ns ns		10 -0.5 2 4 1.8	
transit time weight: maximum ratings:	ns g		15 64	
anode current cathode current gain sensitivity	∝A nA x 10 ⁶ A/Im pC/MeV			100 20 1 50 500
temperature V (k-a) ¹⁾ V (k-d1) V (d-d) ²⁾ ambient pressure (absolute)	°C V V kPa	-55		175 2300 450 300 202

⁽¹⁾subject to not exceeding max. rated sensitivity ⁽²⁾subject to not exceeding max rated V(k-a)

duration60 mins/axissine vibration:30 gamplitude30 gfrequency range50 Hz to 2000 Hzsweep rate2 octaves/minduration60 mins/axisshock (half sine wave):0.5 ms duration0.5 ms duration1000 g peak	sine vibration: amplitude frequency range sweep rate duration shock (half sine wave): 0.5 ms duration	30 g 50 Hz to 2000 Hz 2 octaves/min 60 mins/axis 1000 g peak
4 ms duration250 g peakshocks per axis3 up, 3 down	4 ms duration	250 g peak

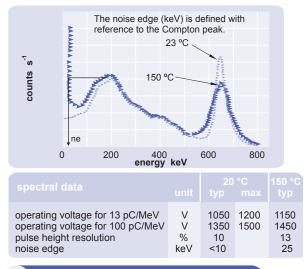
random vibration:	
20 to 100 Hz roll on	6 dB/octave
100 to 400 Hz	0.103 g²/Hz
400 to 500 Hz roll off	6 dB/octave
composite	6.5 g rms
duration	5 mins/axis
microphony at 100 pC/MeV above a	
threshold of 5.5 pC (55 keV)	< 1 cps

8 magnetic field sensitivity



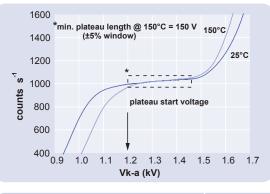
9 pulse height resolution with Nal(TI) crystal

This pmt is tested for resolution at room temperature & at high temperature.



pulse counting with Nal(TI) crystal 10

Pulse counting plateau with ¹³⁷Cs and Nal(TI) crystal (1.0" dia. x 1.5")



		150°C		
combined 25 °C / 150 °C: plateau start (1.5 pC threshold) plateau length ±5 %	V V	150	1200	1500

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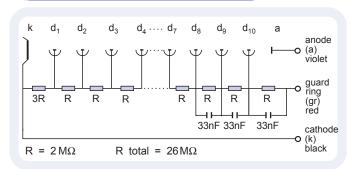
ADIT Electron Tubes 300 Crane Street Sweetwater TX 79556 USA tel: (325) 235 1418 toll free: (800) 399 4557 fax: (325) 235 2872 e-mail: sales@electrontubes.com

25.4 (1.0) pmt dia max active dia 27 (1.07) black violet red guard ring cathode (0.87) anode 71.5 ± 0.5 (gr) (k) (a) (2.81 ± 0.020) 22 photomultiplier and integral VDN

external dimensions in mm (inches)

22 AWG flexible wires, PTFE encapsulated in a mumetal* sleeve insulated length 203 (8.0) minimum

voltage divider distribution 12

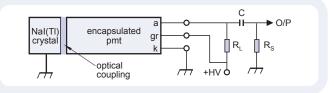


ordering information 13

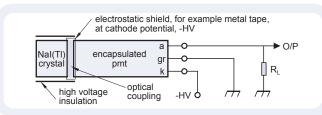
The 9110V02 meets the specification contained in this data sheet. If you want a different specification then discuss your requirements with us. For customer specific requirements, ET Enterprises will change the 2 digit numeric suffix to indicate additional tests and selection.

applications with Nal(TI) crystals 14

The use with positive HV is recommended, as shown in the diagram below:



With negative HV, as shown in the next diagram, any material in contact with the window, for example the Nal(TI) crystal. must be maintained at cathode potential and insulated for safety. The interface between the Nal(TI) crystal and the pmt window must be shielded along the body of the housing.



These precautions are essential to prevent erratic behaviour. *mumetal is a registered trademark of Magnetic Shield Corporation

an ISO 9001 registered company



The company reserves the right to modify these designs and specifications without notice Developmental devices are intended for evaluation and no obligation is assumed for futur manufacture. While every effort is made to ensure accuracy of published information the company cannot be held responsible for errors or consequences arising therefrom.

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